



STPS1L30M

LOW DROP POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	1 A
V_{RRM}	30 V
$T_j(\text{max})$	150°C
$V_F(\text{max})$	0.38 V

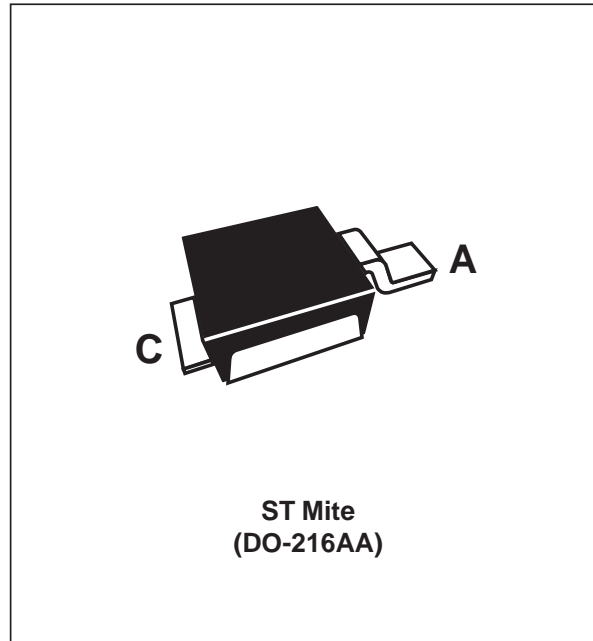
FEATURES AND BENEFITS

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop for higher efficiency & extended battery life
- Low thermal resistance

DESCRIPTION

Single Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in ST Mite, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications. Due to the small size of the package this device fits battery powered equipment (cellular, notebook, PDA's, printers) as well chargers and PCMCIA cards.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	30	V
$I_{F(RMS)}$	RMS forward current	2	A
$I_{F(AV)}$	Average forward current	$T_c = 140^\circ\text{C} \quad \delta = 0.5$	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10 \text{ ms sinusoidal}$	A
T_{stg}	Storage temperature range	- 65 to + 150	°C
T_j	Maximum operating junction temperature*	150	°C
dV/dt	Critical rate of rise of reverse voltage (rated V_r , $T_j = 25^\circ\text{C}$)	10000	V/ μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	20	°C/W
$R_{th(j-a)}$	Junction to ambient with minimum recommended pad size, PC board FR4	250	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Value			Unit
				Min.	Typ.	Max.	
I_R^*	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$		0.13	0.39	mA
		$T_j = 85^\circ\text{C}$			5.25	16.5	
		$T_j = 25^\circ\text{C}$	$V_R = 20\text{ V}$		0.05	0.24	
		$T_j = 85^\circ\text{C}$			3.5	10.5	
		$T_j = 25^\circ\text{C}$	$V_R = 10\text{ V}$		0.03	0.15	
		$T_j = 85^\circ\text{C}$			2.4	7	
V_F^*	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 1\text{ A}$		0.33	0.39	V
		$T_j = 85^\circ\text{C}$			0.28	0.34	
		$T_j = 25^\circ\text{C}$	$I_F = 3\text{ A}$		0.45	0.53	
		$T_j = 85^\circ\text{C}$			0.43	0.51	

Pulse test : * $t_p \leq 380\ \mu\text{s}$, $\delta \leq 2\%$

To evaluate the conduction losses use the following equation :

$$P = 0.34 \times I_{F(AV)} + 0.07 I_{F(RMS)}^2$$

Fig. 1: Conduction losses versus average current.

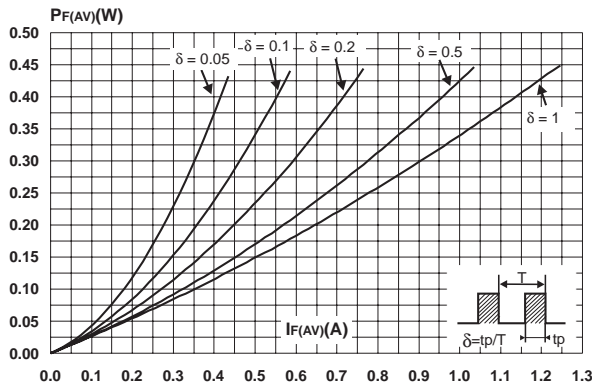


Fig. 2: Average forward current versus ambient temperature ($\delta = 0.5$)

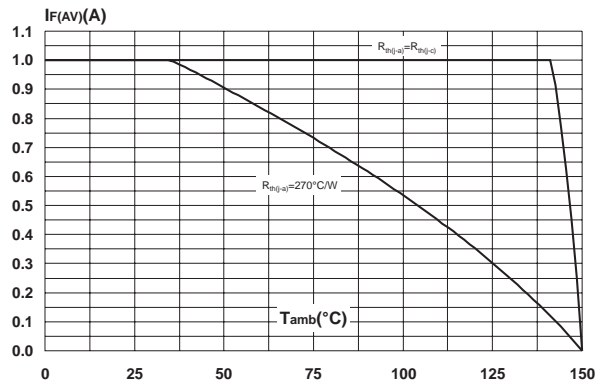


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values).

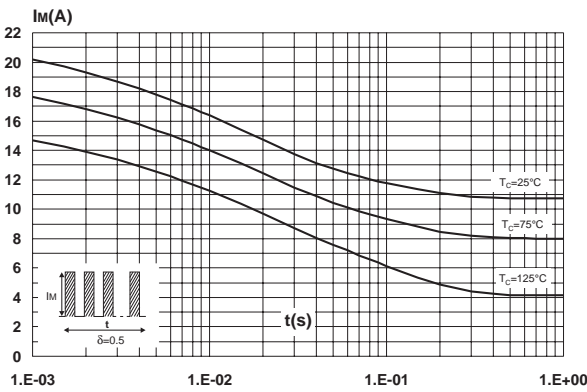


Fig. 4: Relative variation of thermal impedance junction to case versus pulse duration.

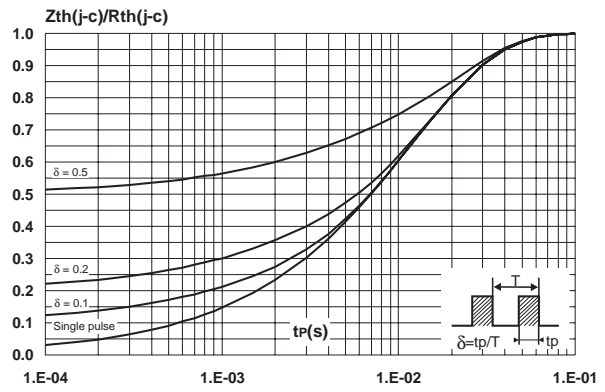


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values).

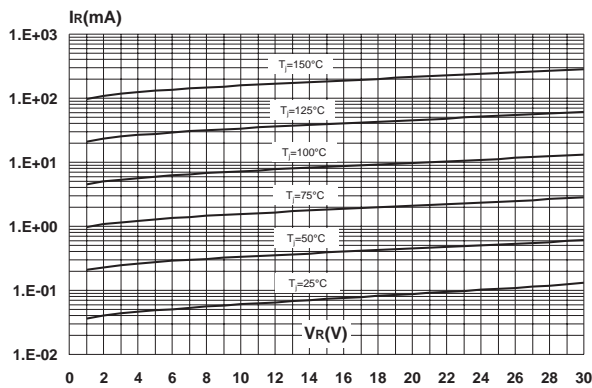


Fig. 6: Reverse leakage current versus junction temperature (typical values).

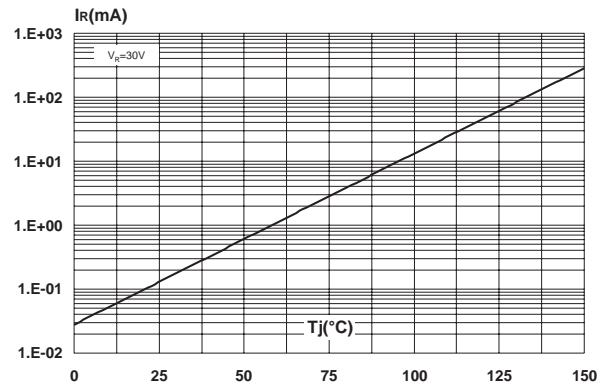


Fig. 7: Junction capacitance versus reverse voltage applied (typical values).

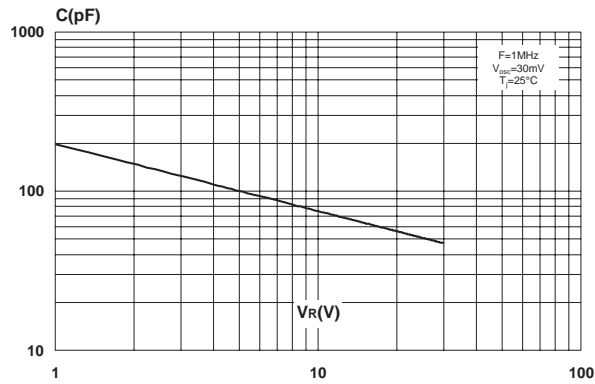


Fig. 8: Forward voltage drop versus forward current.

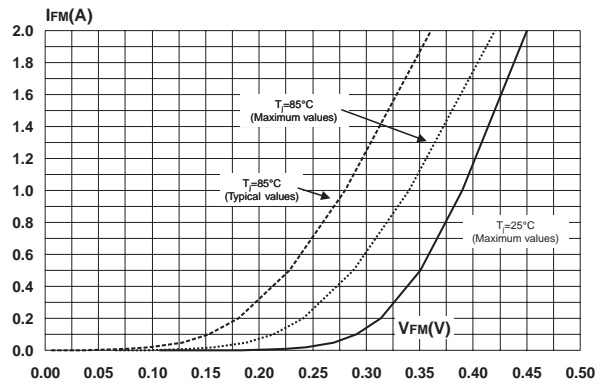
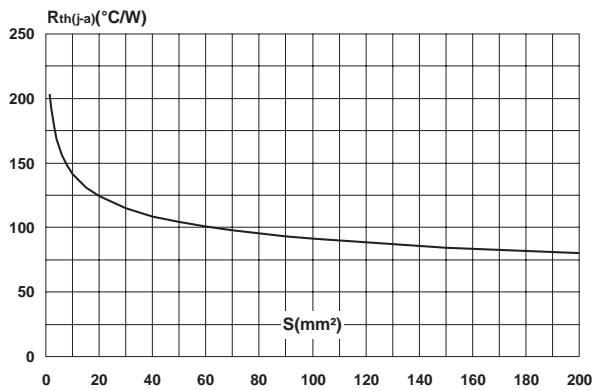
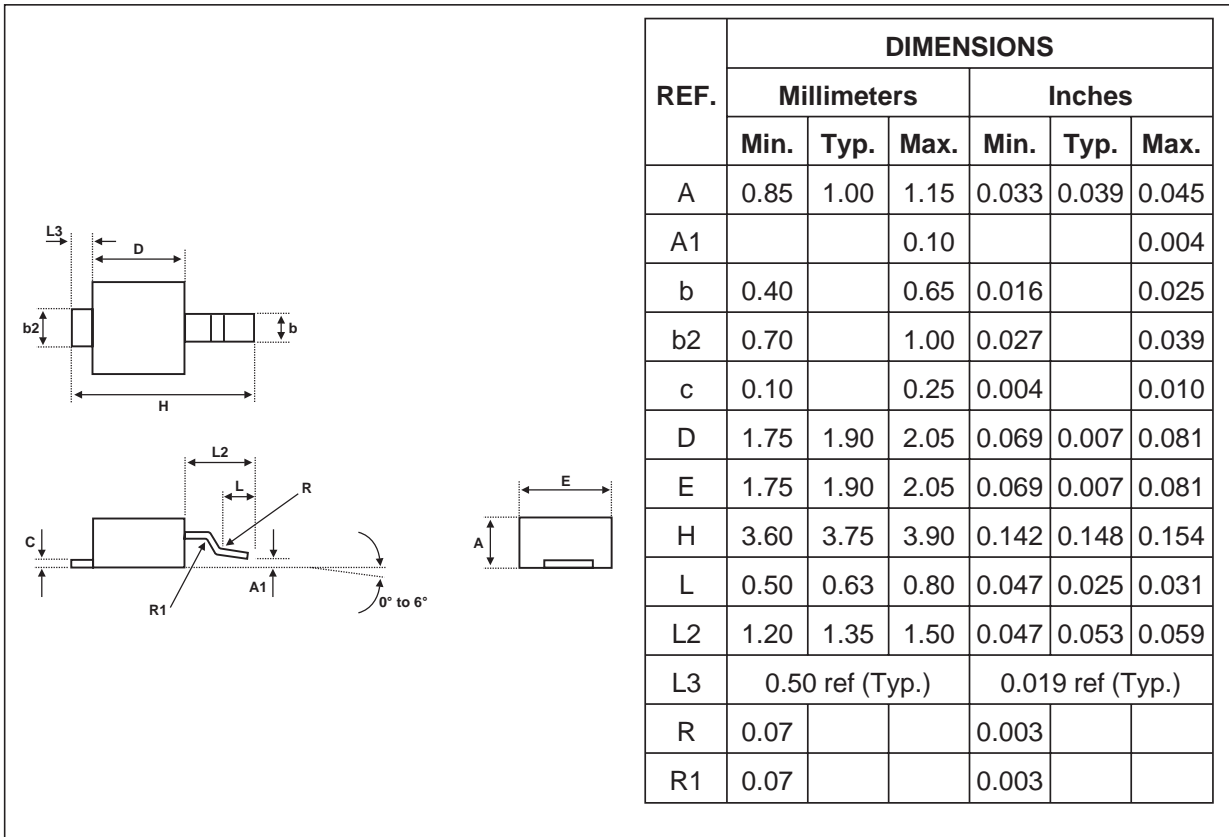


Fig. 9: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, Cu = 35 μm , typical values).

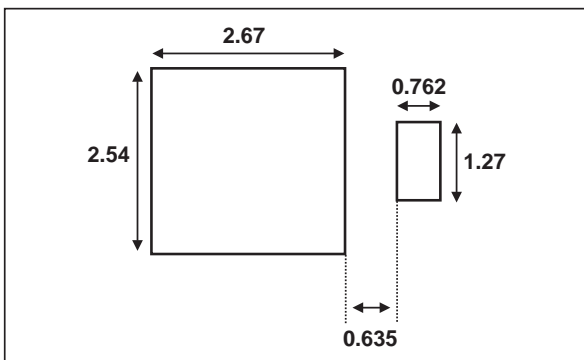


PACKAGE MECHANICAL DATA
ST Mite



Note: The anode is connected to the longer tab
The cathode is connected to the shorter tab (heatsink)

FOOTPRINT (dimensions in mm)



STPS1L30M

Type	Marking	Package	Weight	Base qty	Delivery mode
STPS1L30M	1L3	ST Mite	15.5 mg	12000	Tape & reel

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